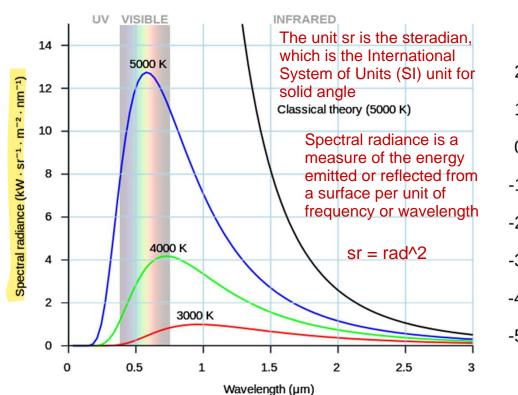
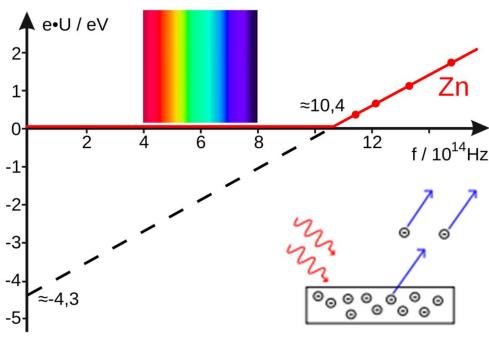
## "Old Quantum Theory": historical perspective





Quantum Stat. Mech.

Black-body radiation (Planck, 1900)

Specific heats of solids (Einstein, 1907)

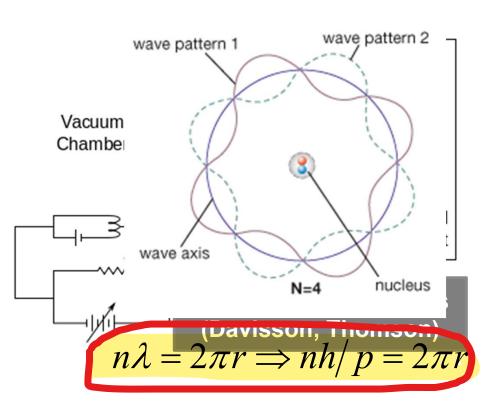
Light emitted and absorbed by 'oscillators' in quanta:  $E_n - E_{n-1} = hv$ 

Photoelectric Effect (Einstein, 1905)

Special Relativity (Finstein, 1905):  $E^2 = (m_0c^2)^2 + (pc)^2$ 

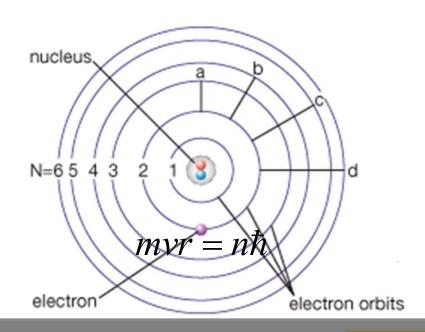
Light is a particle: E = hv  $p = h/\lambda$ 

### "Old Quantum Theory": historical perspective



Matter waves (de Broglie, 1924): λ = h/p

**Electrons are waves!** 



Hydrogen emission spectra (Lyman, Balmer, Paschen, Brackett, Pfund)

# Hydrogen atom (Bohr, 1913)

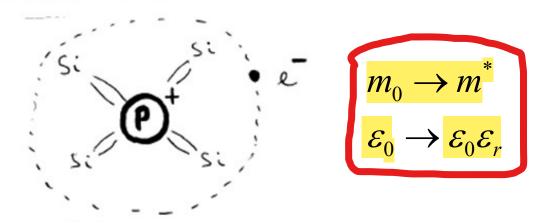
$$E_n = -\frac{m_0 q^4}{2(4\pi\varepsilon_0 n\hbar)^2} = \frac{-13.6eV}{n^2}$$

$$r_n = \frac{4\pi\varepsilon_0 (n\hbar)^2}{m_0 q^2} = 0.53\dot{\mathbf{A}} \cdot n^2$$

### Bohr Model for hydrogen atom

$$r_{n} = \frac{4\pi\varepsilon_{0} (n\hbar)^{2}}{m_{0}q^{2}} = 0.53\dot{A} \cdot n^{2} \qquad E_{n} = -\frac{m_{0}q^{4}}{2(4\pi\varepsilon_{0}n\hbar)^{2}} = \frac{-13.6eV}{n^{2}}$$

#### "HYDROGENIC" MODEL FOR DOPANTS



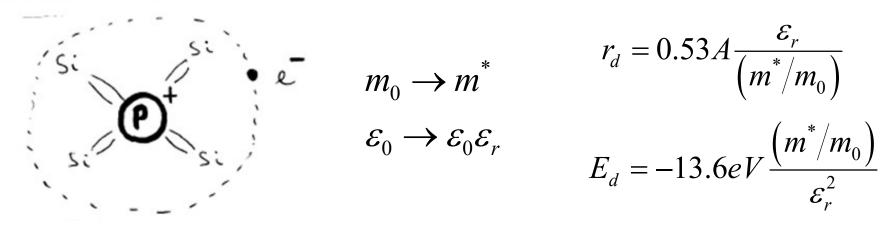
#### Dopants give rise to carriers because:

- a. That is their job, and they understand their job
- b. It is more difficult to ionize inside a semiconductor
- It is easier to ionize inside a semiconductor than in vacuum
  - d. It is always thermodynamically favorable to give up the carrier

Typically, in a semiconductor:  $m^* \sim 0.1 m_0$ ,  $\varepsilon_r \sim 10$   $\Rightarrow r_d \sim 5 nm$ ,  $E_d \sim 10 meV$ 

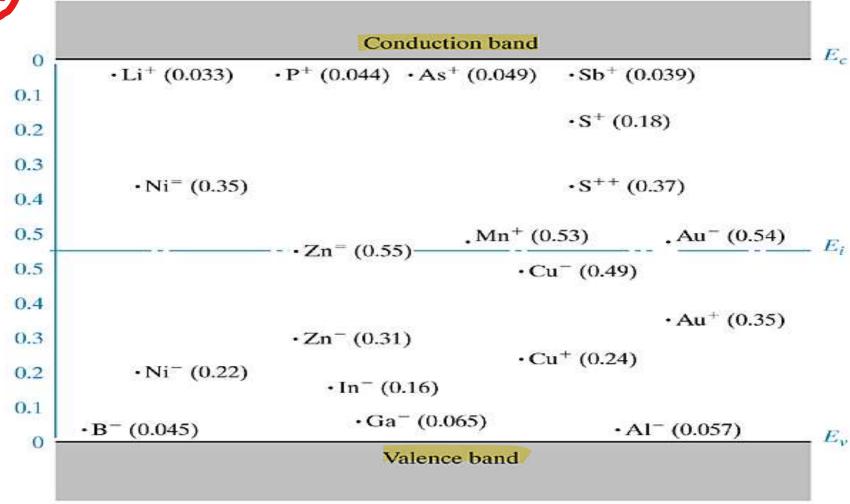
#### Will dopant ionization happen at all temperatures?

#### "HYDROGENIC" MODEL FOR DOPANTS



#### Dopants give rise to carriers because:

- a. That is their job, and they understand their job
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Real impurities: shallow vs. deep, donor/acceptor vs. trap

### Schrödinger Wave Equation

Plane wave amplitude

$$\Psi \sim \exp[i(k x - \omega t)]$$

**Momentum** 

$$p = \frac{h}{\lambda} = \frac{2\pi\hbar}{2\pi/k} = \hbar k \qquad E = h\nu = \hbar\omega$$

**Energy** 

$$E = h\nu = \hbar\omega$$

$$-i\hbar\frac{\partial\Psi}{\partial x} = (\hbar k)\Psi$$

$$p \to -i\hbar \frac{\partial}{\partial x}$$

$$i\hbar \frac{\partial \Psi}{\partial t} = (\hbar \omega) \Psi$$

$$E \to i\hbar \frac{\partial}{\partial t} \cong H$$

$$i\hbar\frac{\partial\Psi}{\partial t} = H\Psi = -\frac{\hbar^2}{2m}\frac{\partial^2\Psi}{\partial x^2} + V\Psi$$

$$H\psi = E\psi$$

**Time-dependent Schrodinger Equation** 

**Time-independent Schrodinger Equation** 

### Solutions to the Schrödinger Equation

$$H_n \psi_n = E_n \psi_n$$
 
$$\Psi = \psi_n(x) e^{-iE_n t/\hbar} \rightarrow \sum_n c_n \psi_n(x) e^{-iE_n t/\hbar}$$

Probability of finding particle in the neighborhood of x:

$$\left|\psi_{n}\right|^{2} = d^{3}x \ \psi_{n}^{*}\psi_{n}$$

**Orthonormal basis** 

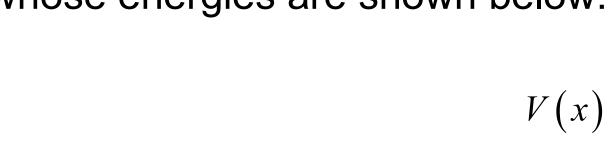
$$\int_{x} d^{3}x \ \psi_{m}^{*} \psi_{n} = \delta_{mn} = 0 \iff m \neq n$$

$$1 \iff m = n$$

Expectation value of operator A (e.g. p,  $p^2/2m + V$ ) in state  $\psi_n$ 

$$\int_{x} d^{3}x \, \psi_{n}^{*} \hat{A} \psi_{n}$$

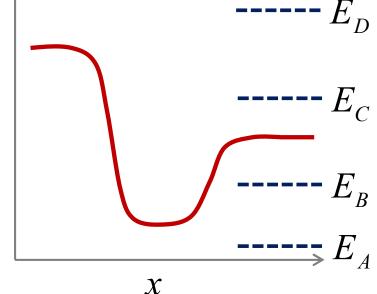
Consider the potential V(x) and the states A, B, C and D whose energies are shown below:



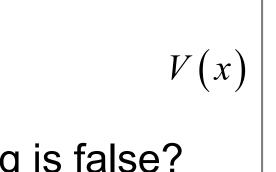
Which of the following is false?



- b. State B is a bound state.
- c. State C is a bound state.
- d. State D is a scattering state.



Consider the potential V(x) and the states A, B, C and D whose energies are shown below:



 $E_{C}$ 

 $\chi$ 

Which of the following is false?

- a. State A cannot exist.
- b. State B is a bound state.
- State C is a bound state.
- d. State D is a scattering state.

### The infinite rectangular well

$$H\psi = E\psi$$

$$\Rightarrow \left(\frac{p^2}{2m} + V\right)\psi = E\psi$$

$$\Rightarrow \frac{-\hbar^2}{2m} \frac{d^2 \psi}{dx^2} + V(x)\psi = E\psi$$

#### Inside well

$$\frac{-\hbar^2}{2m}\frac{d^2\psi}{dx^2} = E\psi \Rightarrow \frac{d^2\psi}{dx^2} = -k^2\psi$$

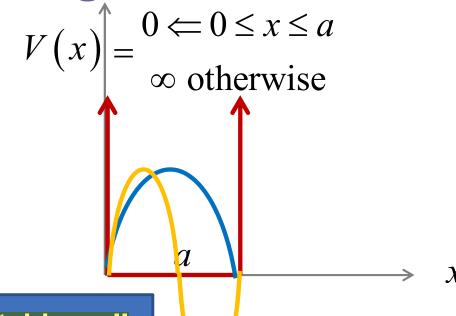
$$\Rightarrow \psi = A \sin(kx) + B \cos(kx), \ k = \sqrt{2mE/\hbar^2}$$

# Boundary condition: ψ is continuous

$$\psi(0) = 0$$
  $\psi(a) = 0$   
 $\Rightarrow B = 0$   $\Rightarrow ka = n\pi$ 

$$\psi_n = A \sin\left(\frac{n\pi x}{a}\right)$$

$$E_n = \frac{\hbar^2 n^2 \pi^2}{2ma^2}$$



#### Outside well

$$\psi(x) = 0$$

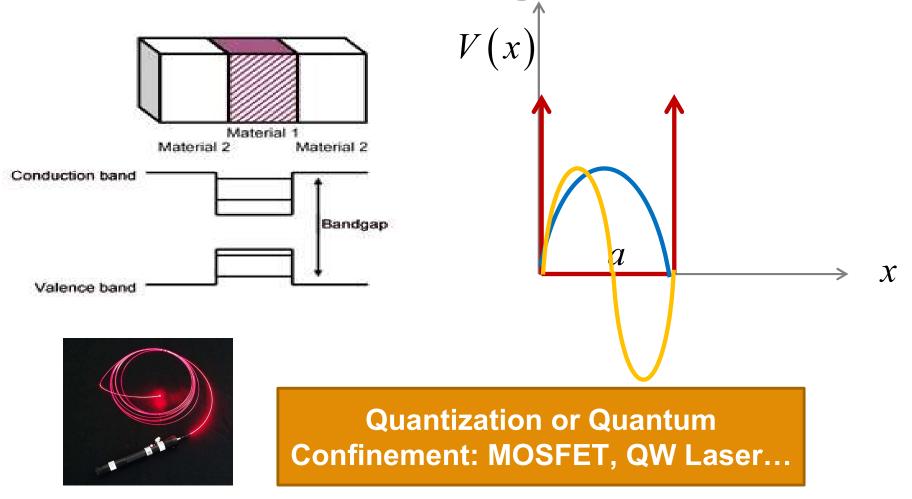
#### Normalization

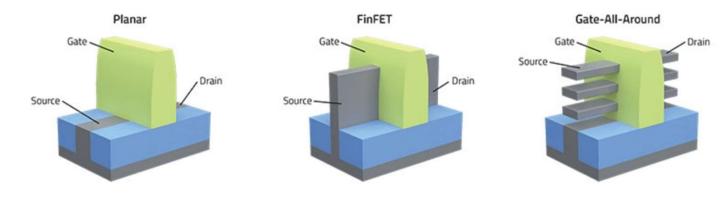
$$\int_{0}^{\infty} dx \left| \psi_{n} \right|^{2} = 1$$

$$\int_{-\infty}^{\infty} dx |A|^2 \sin^2\left(\frac{n\pi x}{a}\right) = 1$$

$$\Rightarrow A = \sqrt{2/a}$$

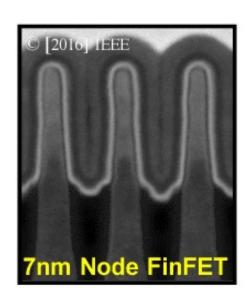
## The infinite rectangular well

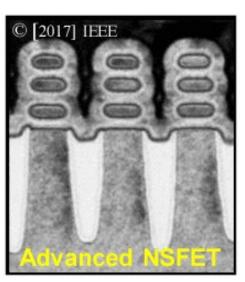




Consider electrons at the bottom of the conduction band in a semiconductor fin (see figure) at room temperature. Assume  $m^* = m_0$  for this semiconductor. The fin thickness for which one needs to consider quantum confinement of electrons in the fin is less than about:

- a. 10 Å
- b. 100 Å
- c. 1000 Å
- d. Never





Consider electrons at the bottom of the conduction band in a semiconductor fin (see figure) at room temperature. Assume  $m^* = m_0$  for this semiconductor. The fin thickness for which one needs to consider quantum confinement of electrons in the fin is less than about:

- a. 10 Å
- b. 100 Å
- c. 1000 Å
- d. Never

$$E - E_C = \frac{p^2}{2m^*} \sim k_B T$$

$$\Rightarrow p = \sqrt{2m^* k_B T}$$

$$p = \hbar k = \frac{h}{\lambda}$$

$$\Rightarrow \lambda = \frac{h}{\sqrt{2m^* k_B T}} = 7.6nm$$

### The delta-function barrier

#### **Delta-function**

$$\delta(x) = 0 \Longleftrightarrow x \neq 0$$

$$\int_{-\infty}^{+\infty} \delta(x) dx = 1$$

$$\Rightarrow \int_{-\infty}^{+\infty} f(x+a)\delta(x)dx = f(a)$$

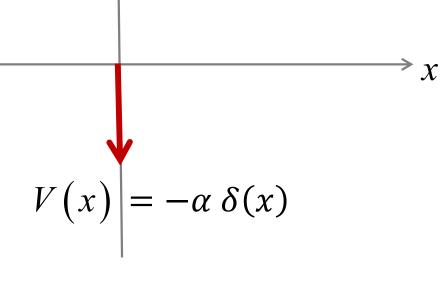
#### x < 0

$$\frac{-\hbar^2}{2m}\frac{d^2\psi}{dx^2} = E\psi \Rightarrow \frac{d^2\psi}{dx^2} = \kappa^2\psi$$

$$\kappa = \left(\frac{2m(-E)}{\hbar^2}\right)$$

#### x > 0

$$\psi = C_+ e^{-\kappa x}$$



$$\Rightarrow \psi = C_- e^{+\kappa x}$$

Boundary condition: ψ is continuous

$$C_- = C_+ = \psi(0)$$

### The delta-function barrier

#### x < 0

$$\psi = \psi(0)e^{+\kappa x}$$

#### x > 0

$$\psi = \psi(0)e^{-\kappa x}$$

Boundary condition: ψ' is continuous unless V is ∞

$$V(x) = -\alpha \, \delta(x)$$

$$\int_{0}^{0+} dx \left[ \frac{-\hbar^2}{2m} \frac{d^2 \psi}{dx^2} - \alpha \cdot \delta(x) \psi \right] = \int_{0}^{0+} dx \cdot E\psi$$

$$\Rightarrow \frac{-\hbar^2}{2m} \left[ \frac{d\psi}{dx} \right]_{0^-}^{0^+} - \alpha \cdot \psi(0) = 0 \Rightarrow \Delta \psi'(0) = -\frac{2m\alpha}{\hbar^2} \psi(0)$$

$$\Delta \psi'(0) = -\kappa \psi(0) - \kappa \psi(0) = -2\kappa \psi(0) = -\frac{2m\alpha}{\hbar^2} \psi(0) \Rightarrow \kappa = \frac{m\alpha}{\hbar^2}$$

$$\Rightarrow -\frac{2mE}{\hbar^2} = \left(\frac{m\alpha}{\hbar^2}\right)^2 \Rightarrow E = -\frac{m\alpha^2}{2\hbar^2}$$

### **Finis**

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